



The Ag effect on magnetic properties and microstructure of FePt/Ag₂Te particulate films

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ABSTRACT

A [FePt (1 nm)/Ag₂Te(*t*)]₁₀ (thickness *t* = 0.1–0.3 nm) multilayer was deposited alternately on glass substrate and subsequently annealed by a rapid thermal process (RTP). After the RTP, the interface between FePt and Ag₂Te was intermixed, forming particulate films. The L₁₀ FePt grain size decreases from 23 to 14 nm as *t* of the Ag₂Te intermediate layer increases from 0.1 to 0.3 nm. The (FePt/Ag₂Te)₁₀ particulate film shows perpendicular magnetization. Compared to (FePt/Ag₂Te)₁₀, the Ag/(FePt/Ag₂Te)₁₀/Ag multilayer also shows perpendicular magnetization with less *c*-axis dispersion. The Ag capping and seed layers reduce the ordering temperature of FePt but facilitate its grain growth during RTP. As a result, the FePt grains are refined and well-separated by the Ag₂Te phase, but change to a continuous film after inserting Ag capping and seed layers.

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1. Introduction

(001) textured L₁₀ FePt thin film has high magnetocrystalline anisotropy field and good corrosion resistance, which are required for hard magnetic materials and for high-density magnetic recording media. Due to its high uniaxial anisotropy, the super-paramagnetic limit was extended and thermal stability was achieved, even when the grain size of FePt was reduced to 5 nm [1–4]. Granular type magnetic recording media was used conventionally, however, maintaining the signal to noise ratio with increasing recording density requires magnetic media with smaller grain size. This decrease in grain size and exchange coupling are usually achieved by adding materials, such as amorphous MgO, B₂O₃, SiO₂, Al₂O₃, and AlN into FePt film or a Fe/Pt multilayer and forming the granular structure after annealing. L₁₀ FePt film with perpendicular magnetization was prepared by creating an appropriate epitaxial buffer layer on a single crystal substrate [5–7], or by forming the *c*-axis texture on an amorphous substrate [8–10]. FePt films with a thin Ag layer have been discussed extensively, due to the immiscibility of FePt and Ag [11–13]. (001) textured FePt:TiO₂, (Fe/Pt/SiO₂)_x nanocomposite films, composed of isolated 5 nm grains of FePt have been reported [14,15]. In our previous work, the Ag/FePt bilayer and Ag/FePt/Ag trilayer annealed by a rapid thermal process (RTP) at 800 °C are continuous films with perpendicular magnetization [16]. Ag has a high thermal diffusivity that reduces the ordering temperature of FePt, yet enhances

grain growth during RTP. In this study, we compared the magnetic properties and microstructure of multilayer (FePt/Ag₂Te)₁₀, and Ag/(FePt/Ag₂Te)₁₀/Ag. The intermetallic compound Ag₂Te has a low melting point (960 °C) almost equal to that of Ag (962 °C). Metallic Ag has limited solubility (~6.9%) in L₁₀ FePt that is not suitable for isolation of FePt grains at a high annealing temperature. The Ag₂Te compound has a covalent/ionic character with higher resistivity [1–4 × 10⁻³ Ω m] than metallic Ag [1.587 × 10⁻⁸ Ω m]. The bonding characteristic of Ag₂Te is similar to that of SiO₂, TiO₂, and MgO, and better for the FePt matrix than Ag. The Ag₂Te is also a thermoelectric material with low thermal conductivity and a high-power factor, which is defined as the square of the Seebeck coefficient times the electrical conductivity [17].

2. Experimental

The multilayers [FePt (1 nm)/Ag₂Te(*t*)]₁₀ (thickness *t* = 0.1–0.3 nm), Ag (1 nm)/[FePt (1 nm)/Ag₂Te(*t*)]₁₀/Ag (0.1 nm) were fabricated by DC magnetron sputtering. The base pressure of the sputtering system was 5 × 10⁻⁸ Torr and the working pressure was 1.5 × 10⁻³ Torr under high purity argon gas. FePt, Ag₂Te, and Ag targets were used, and the films were deposited on a glass substrate. After deposition, the films were annealed by a rapid thermal annealing (RTA) system at 800 °C for 10 min. The heating rate in RTA is 10 °C/s much higher than in a traditional furnace. The crystal structure of samples was identified by grazing incident X-ray diffractometry (XRD) with Cu Kα radiation. The microstructure of the films was observed by high resolution transmission electron microscopy (HRTEM). Magnetic hysteresis loops were measured at room temperature using a vibration sample magnetometer (VSM) with a maximum magnetic field of 2 T.

3. Results and discussion

Fig. 1 shows XRD patterns of the single-layer FePt, multilayer [FePt/Ag₂Te (*t*)]₁₀ (*t* = 0.1, 0.3, and 0.4 nm, respectively), trilayer

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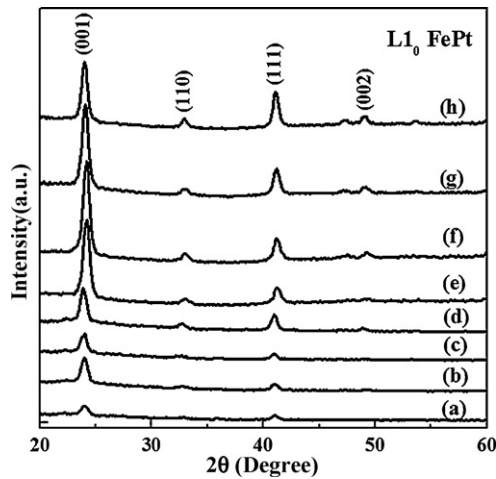


Fig. 1. XRD patterns of films annealed at 800 °C for 10 min: (a) FePt single layer, (b) [FePt/Ag₂Te(*t*)]₁₀ multilayers, *t* = 0.1 nm, (c) *t* = 0.3 nm, (d) *t* = 0.4 nm; (e) Ag/FePt/Ag trilayer, (f) Ag/[FePt/Ag₂Te(*t*)]₁₀/Ag multilayer, *t* = 0.1 nm, (g) *t* = 0.3 nm, (h) *t* = 0.4 nm.

Ag/FePt/Ag and multilayer Ag/[FePt/Ag₂Te (*t*)]₁₀/Ag annealed at 800 °C for 10 min. For the FePt single layer and Ag/FePt/Ag trilayer shown in Fig. 1(a) and (e), the film showed preferential orientation in the [001] direction. The relative intensity of the fundamental peak (111) is low. The XRD patterns of the multilayers [FePt/Ag₂Te(*t*)]₁₀ and Ag/[FePt(1 nm)/Ag₂Te(*t*)]₁₀/Ag (*t* = 0.1, 0.3, and 0.4 nm, respectively) are plotted in Fig. 1(b–d) and (f–h), respectively. The superlattice diffraction peak (001) dominates and the low intensity of the (111) peak is also indexed. When *t* = 0.4 nm, the relative intensity of the (111) peak is increased to half that of the (001) peak, indicating that FePt grains are tend to orient isotropically. In summary, the FePt (001) orientation is deteriorated by inserting an Ag₂Te layer, but is still dominant in the multilayers.

The semi-quantitative method, the Lotgering orientation factor (LOF), was used to analyze the variation of the (001) preferred orientation. The LOF represents the degree of specific texture and has values ranging from 0 to 1, where 0 and 1 indicate a random distribution and perfect crystal orientation, respectively. When the specific orientation is {001}, the LOF is defined as follows [19]:

$$\text{LOF} = \frac{P - P_0}{1 - P_0}$$

$$\text{where } P = \frac{\sum (001)_{\text{sample}}}{\sum (hkl)_{\text{sample}}}, \quad P_0 = \frac{\sum (001)_{\text{powder}}}{\sum (hkl)_{\text{powder}}} \quad (1)$$

For the calculation of sample orientation, the *P* value was estimated from the intensity summation of the {001} orientation over the intensity summation of (*hkl*) reflections ranging from 20 to 80°. For the non-oriented sample (*P*₀ value), the simulation data was used to replace the free textured FePt powder sample. Table 1 lists the LOF values of a single-layer FePt, multilayer [FePt/Ag₂Te (*t*)]₁₀ (*t* = 0.1, 0.3, and 0.4 nm, respectively), trilayer Ag/FePt/Ag, and multilayer Ag/[FePt/Ag₂Te (*t*)]₁₀/Ag annealed at 800 °C for 10 min. The trilayer Ag/FePt/Ag (0.73) has a higher LOF value than single-layer FePt (0.49). For the multilayers [FePt/Ag₂Te (*t*)]₁₀, Ag/[FePt/Ag₂Te (*t*)]₁₀/Ag (*t* = 0.1 and 0.3 nm, respectively), the similar LOF values are 0.69, 0.65 and 0.70, 0.63, respectively. However, the in-plane magnetic hysteresis loops are more linear in the multilayer Ag/[FePt/Ag₂Te (*t*)]₁₀/Ag (*t* = 0.1, 0.3) shown in Fig. 3(e) and (f). When the thickness of the Ag₂Te layer reaches 0.4 nm per pair in the multilayer [FePt/Ag₂Te (*t*)]₁₀, Ag/[FePt/Ag₂Te

Table 1

The LOF, FWHM, and (001) peak values of a single-layer FePt, multilayer [FePt/Ag₂Te (*t*)]₁₀ (*t* = 0.1, 0.3 and 0.4 nm, respectively), trilayer Ag/FePt/Ag and multilayer Ag/[FePt/Ag₂Te (*t*)]₁₀/Ag annealed at 800 °C for 10 min.

XRD	2θ (001)	Δθ	FWHM	LOF
(a) FePt single layer	23.99	–	0.63	0.49
(b) (FePt/Ag ₂ Te (0.1 nm)) ₁₀	23.98	–	0.56	0.69
(c) (FePt/Ag ₂ Te (0.3 nm)) ₁₀	23.91	–	0.58	0.65
(d) (FePt/Ag ₂ Te (0.4 nm)) ₁₀	23.89	–	0.54	0.49
(e) Ag/FePt/Ag trilayer	24.16	(e)–(a) 0.17	0.58	0.73
(f) Ag/[FePt/Ag ₂ Te (0.1 nm)] ₁₀ /Ag	24.15	(f)–(b) 0.17	0.58	0.70
(g) Ag/[FePt/Ag ₂ Te (0.3 nm)] ₁₀ /Ag	24.15	(g)–(c) 0.24	0.57	0.63
(h) Ag/[FePt/Ag ₂ Te (0.4 nm)] ₁₀ /Ag	24.16	(h)–(d) 0.27	0.53	0.40

(*t*)]₁₀/Ag, the LOF values decrease to 0.49 and 0.39, respectively.

The ordering degree *S* is not easy to estimate by lattice constants *c* (*c*-axis spacing) over *a* (*a*-axis spacing), *c/a* ratio, from the (001) and (110) peaks or from the intensity ratio of the (001) and (002) peaks (*I*₍₀₀₁₎/*I*₍₀₀₂₎) due to the weak diffraction peaks of (110), and (002). In Table 1, for the same thickness of the inserted Ag₂Te layer, the (001) peak shifts to higher angles, as evident from Fig. 1(e)–(a), Fig. 1(f)–(b), Fig. 1(g)–(c), and Fig. 1(h)–(d), respectively, indicating that the lattice constant *c* is decreased. The ordering of the multilayer Ag/[FePt/Ag₂Te(*t*)]₁₀/Ag is better than that of [FePt/Ag₂Te(*t*)]₁₀.

The *c*-axis distribution can be explained more quantitatively by the full width of half maximum (FWHM) variations of the FePt (001) diffraction peaks and are listed in Table 1. The FWHM values for the multilayers [FePt/Ag₂Te (*t*)]₁₀, Ag/[FePt/Ag₂Te (*t*)]₁₀/Ag (*t* = 0.4 nm) were discarded because of low LOF values. The *c*-axis of the trilayer Ag/FePt/Ag (FWHM, 0.58) is less dispersed than that of the single-layer FePt (0.63). For the multilayers [FePt/Ag₂Te (*t*)]₁₀, Ag/[FePt/Ag₂Te (*t*)]₁₀/Ag (*t* = 0.1 and 0.3 nm, respectively), the similar FWHM values are 0.56, 0.58 and 0.58, 0.57, respectively. The *c*-axis dispersion of the multilayers is nearly the same.

Fig. 2 shows the magnetic hysteresis loops of single-layer FePt, multilayer [FePt/Ag₂Te(*t*)]₁₀ (*t* = 0.1 and 0.3 nm, respectively), trilayer Ag/FePt/Ag and multilayer Ag/[FePt/Ag₂Te(*t*)]₁₀/Ag annealed at 800 °C for 10 min. Fig. 2(a) shows the in-plane and out-of-plane hysteresis loops of the FePt single layer annealed at 800 °C and shows that it presents perpendicular magnetization. In Fig. 2(a), the out-of-plane *H*_c and remanence ratio are 9.8 kOe and 0.93, respectively. The in-plane magnetic hysteresis loop is linear. Fig. 2(b) and (c) show the in-plane and out-of-plane hysteresis loops of the multilayers [FePt/Ag₂Te(*t*)]₁₀ (*t* = 0.1 and 0.3 nm) annealed at 800 °C. The out-of-plane coercivity and remanence are higher than the in-plane properties for (FePt/Ag₂Te) films. The FePt/Ag₂Te presents perpendicular magnetization with the out-of-plane *H*_c (10.1 kOe) and remanence ratio (0.84) when the total thickness of Ag₂Te reaches 3 nm (0.3 nm per pair). The high value of in-plane *H*_c is due to *c*-axis dispersion but the remanence ratio (*M*_r/*M*_s = 0.32) is low. Fig. 2(d) shows in-plane and out-of-plane hysteresis loops of trilayer Ag/FePt/Ag film. The film also shows perpendicular magnetization with the out-of-plane *H*_c (9.1 kOe) and remanence ratio (0.95). Fig. 2(e) and (f) show the in-plane and out-of-plane hysteresis loops of the multilayers Ag/[FePt/Ag₂Te(*t*)]₁₀/Ag (*t* = 0.1, 0.3 nm) annealed at 800 °C. In Fig. 2(e) and (f), the films show perpendicular magnetization with higher out-of-plane *H*_c than seen in multilayer (FePt/Ag₂Te) films. As shown in Fig. 2(e) and (f), the out-of-plane *H*_c and remanence ratio are 9.4 and 11.5 kOe, 0.92 and 0.87, respectively. Compared with Fig. 2(b) and (c), the in-plane hysteresis loop is nearly linear.

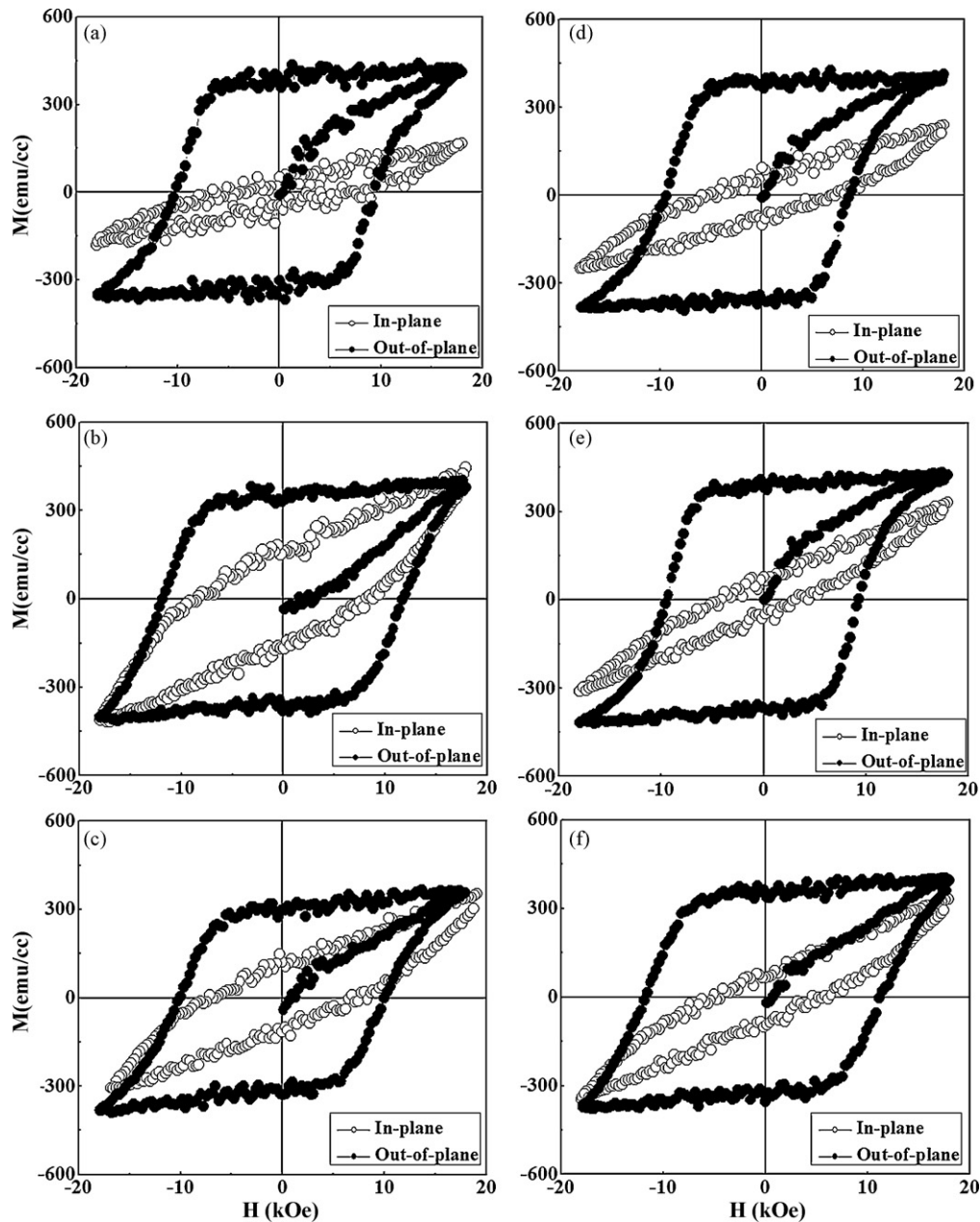


Fig. 2. In-plane and out-of-plane magnetic hysteresis loops of (a) FePt single layer, (b) $[\text{FePt}/\text{Ag}_2\text{Te}(t)]_{10}$ multilayer, $t=0.1$ nm, (c) $t=0.3$ nm; (d) Ag/FePt/Ag trilayer, (e) Ag/ $[\text{FePt}/\text{Ag}_2\text{Te}(t)]_{10}$ /Ag multilayer, $t=0.1$ nm, (f) $t=0.3$ nm.

Fig. 3 shows plane view TEM images and selective area diffraction patterns (SAD) of single-layer FePt, trilayer Ag/FePt/Ag and the multilayers $(\text{FePt}/\text{Ag}_2\text{Te})_{10}$, $\text{Ag}/(\text{FePt}/\text{Ag}_2\text{Te})_{10}/\text{Ag}$, respectively. In Fig. 3(a), the image of FePt film annealed at 800°C for 10 min shows that the FePt grains are distributed continuously on the glass substrate and the grain size is not uniform. The ring patterns of the (110), (002) and (111) planes were indexed. Fig. 3(b) and (c) show images of the multilayers $(\text{FePt}/\text{Ag}_2\text{Te}(t))_{10}$ ($t=0.1$ and 0.3 nm) annealed at 800°C for 10 min. In Fig. 3(b), the FePt grains are separated by 1 nm of Ag_2Te and form a particle-like structure. The FePt grains are round and distributed separately. The twin bands used to release phase transition strains are observed in some FePt grains, and the average grain size is 23 nm. Fig. 3(c) shows TEM images of $[\text{FePt}/\text{Ag}_2\text{Te}(0.3\text{ nm})]_{10}$ film annealed at 800°C the grains are refined and the average grain size is 14 nm. In summary, the FePt grains are refined and isolated well by the intermetallic compound Ag_2Te layer. Fig. 3(d) shows the image of

trilayer Ag/FePt/Ag annealed at 800°C for 10 min; the FePt grains are distributed nearly continuously with some network structure. Fig. 3(e) and (f) show images of multilayer $\text{Ag}/(\text{FePt}/\text{Ag}_2\text{Te}(t))_{10}/\text{Ag}$ ($t=0.1$ and 0.3 nm) annealed at 800°C for 10 min; the FePt grains are not distributed continuously and present a network structure. In Fig. 3(e) and (f), the FePt grains are located between networks indicated by arrows; the average grain sizes are 11 and 3 nm. According to Pauling's electronegativity, the ionic character (%) = $\{1 - \exp[-(0.25)(X_{\text{Ag}} - X_{\text{Te}})^2]\} \times 100$, the covalent character of Ag_2Te is 46.1% and ionic character is 53.1% nearly equals to the properties of SiO_2 (51%). The surface energy of glass, Ag_2Te , and FePt are 1.5, 2.1, and 2.8 J/m^2 , respectively [9,18]. This result is similar to that the FePt grains in an oxide matrix such as SiO_2 , TiO_2 or MgO .

The Wohlfarth relation and Kelly–Henkel plot (δM plot) were used to characterize and classify the hysteresis phenomena, especially the intergrain magnetic interaction. The δM plot can be

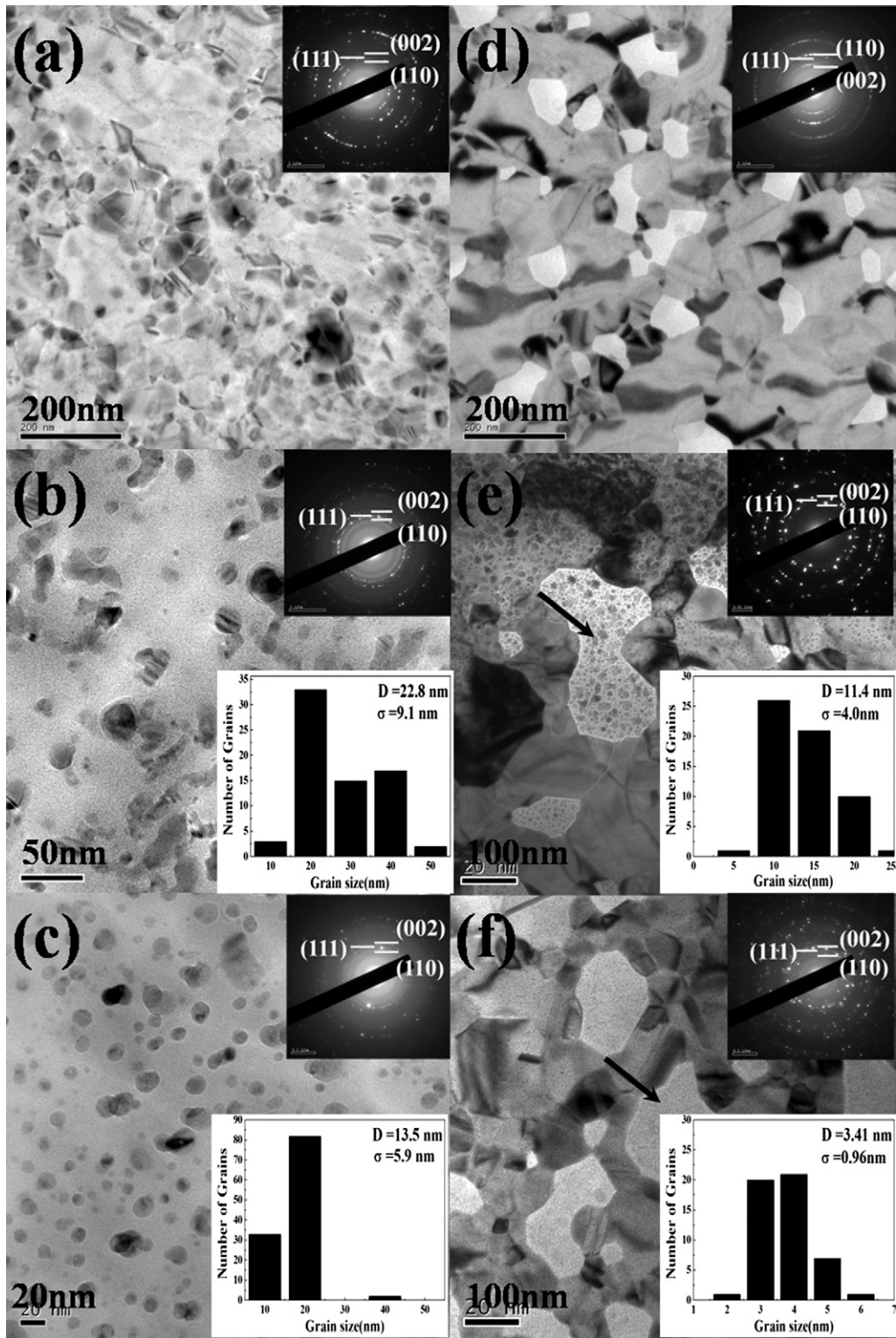


Fig. 3. TEM images of films annealed at 800 °C for 10 min: (a) FePt single layer, (b) [FePt/Ag₂Te(*t*)]₁₀ multilayer, *t*=0.1 nm, (c) *t*=0.3 nm; (d) Ag/FePt/Ag trilayer, (e) Ag/[FePt/Ag₂Te(*t*)]₁₀/Ag multilayer, *t*=0.1 nm, (f) *t*=0.3 nm.

determined from the following equation:

$$\delta M = M_d(H) - [1 - 2M_r(H)] \quad (2)$$

where $M_d(H)$ is the normalized dc-demagnetization(DCD) remanence as a function of the reversal field, and $M_r(H)$ is the normalized isothermal remanence (IRM) curve. From the Kelly–Henkel plot,

a positive δM indicates that intergrain interactions are ferromagnetic exchange interactions. A negative δM value suggests that intergrain interactions are dipolar interactions. Fig. 4 shows the δM plots of a FePt single layer, Ag/FePt/Ag trilayer, and multilayers (FePt/Ag₂Te)₁₀, Ag/(FePt/Ag₂Te)₁₀/Ag. The FePt single layer, Ag/FePt/Ag trilayer, and Ag/(FePt/Ag₂Te)₁₀/Ag multilayer show

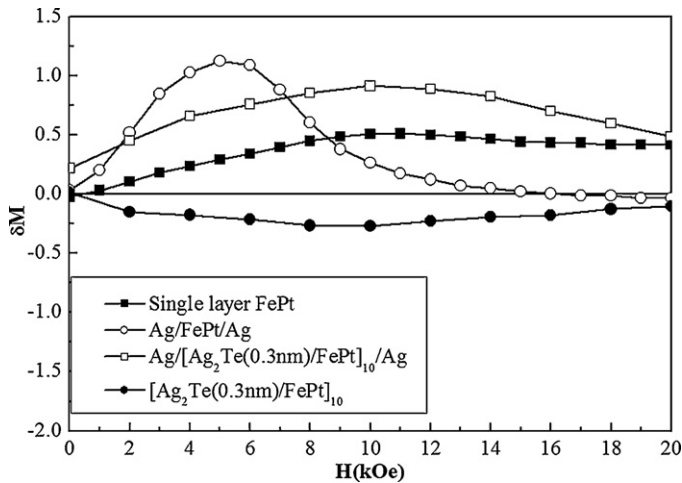


Fig. 4. δM plots of FePt single layer, Ag/FePt/Ag trilayer, multilayers (FePt/Ag₂Te)₁₀, Ag/(FePt/Ag₂Te)₁₀/Ag.

positive δM values which means a strong intergrain exchange interaction. The (FePt/Ag₂Te)₁₀ multilayer without an Ag layer shows a negative δM value at all applied fields. The reduction of exchange interaction between FePt grains was achieved by inserting Ag₂Te inserting layers.

4. Conclusions

In conclusion, FePt film with a perpendicular magnetization was fabricated on a glass substrate and the FePt grains are isolated well by the Ag₂Te phase. The grain size is reduced from hundreds

of nanometers in FePt continuous films to 14 nm in particulate [FePt/Ag₂Te (3 nm)] films.

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